Supporting Information

for

Partially Oxidized Ti₃C₂T_x MXenes for Fast and Selective Detection of Organic Vapors at Part-per-Million Concentrations

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Supporting Figures

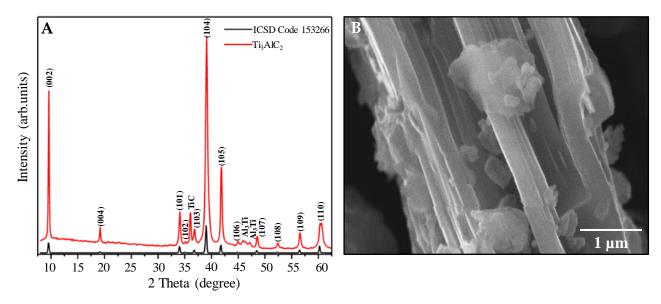


Figure S1. MAX phase characterization. (A) XRD pattern and (B) SEM image of Ti_3AlC_2 MAX phase powder used as a precursor for the MXene synthesis. The XRD pattern shows peaks corresponding to Ti_3AlC_2 (ICSD 153266); only small amounts of TiC and Al₃Ti are identified as by-product phases. SEM image of Ti_3AlC_2 demonstrates a compact layered structure of particles that are typical for MAX phases

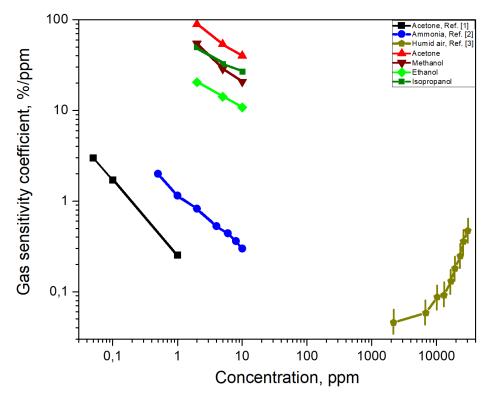


Figure S2. Comparison of gas response data obtained in this work *versus* the results reported in literature on the MXene-based structures.

Ref. [1] *ACS Nano*, **2018**, *12*, 986-993: Kim S.-J. et al. Metallic $Ti_3C_2T_x$ MXene Gas Sensors with Ultrahigh Signal-to-Noise Ratio;

Ref. [2] *Sensors and Actuators B*, **2019**, *298*, 126874: Tai, H. et al. "Enhanced ammonia response of $Ti_3C_2T_x$ nanosheets supported by TiO_2 nanoparticles at room temperature";

Ref. [3] *ACS Applied Materials & Interfaces*, **2019**, in press: Li N. et al. "High Performance Humidity Sensor Based on Urchin-like Composite of Ti₃C₂ MXene-derived TiO₂ Nanowires".

The gas sensitivity coefficient is calculated as $\alpha = S/K$ where $S = \Delta G/G_{air}$, K is the gas concentration in ppm, ΔG is the sensor conductance change due to the gas exposure and G_{air} is the sensor conductance in pure air. In case of data published in Ref. [3], $S = \Delta C/C_{air}$ where ΔC and C_{air} are the sensor capacitance change due to the gas exposure and the capacitance in pure air, respectively. The data acquired from Ref. [3] are delivered for 20-30 °C range because the authors have not reported the exact temperature under "room temperature" conditions

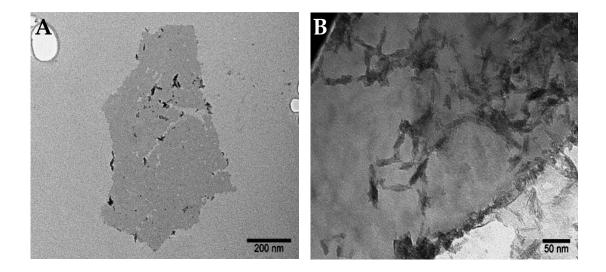


Figure S3. TEM image of MXene flake before (A) and after oxidation (B). MXenes flakes are atomically thin with irregular shapes and sizes. We observed the presence of a few tiny black impurities predominantly at the edges of flakes before the oxidation which are attributed to titanium dioxide. After the oxidation, almost the entire surface of flakes is covered with elongated particles

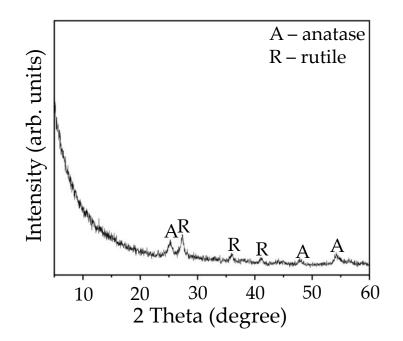


Figure S4. XRD pattern of MXene flakes after the oxidation at 600 °C in air

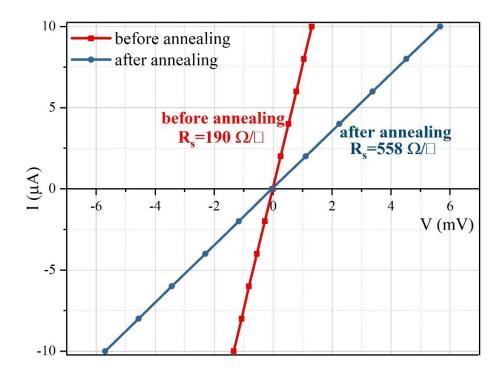


Figure S5. I-V dependence for the MXene film before and after annealing in air at 350 °C

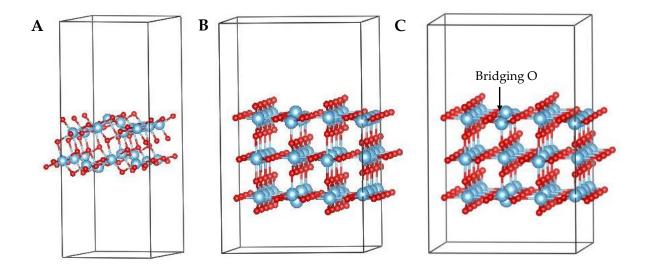


Figure S6. (A) (101) and (B), (C) (110) surface slabs of anatase and rutile structures, respectively. Blue circles are titanium atoms, small red circles are the oxygen atoms. The most prominent feature on rutile (110) surface is the presence of low-coordinated oxygen in the outermost layer. These oxygen atoms are referred to as bridging oxygens (Fig. C). They can be easily removed to introduce defects on a surface^{S1}

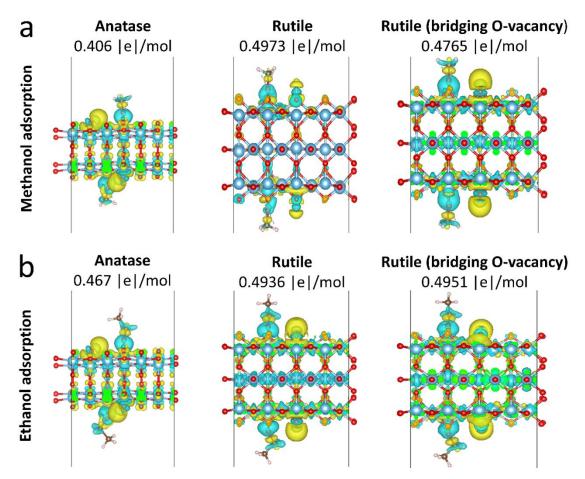


Figure S7. Electron density distributions in TiO_2 of various phases under adsorption of alcohol molecules: (a) case of methanol, (b) case of ethanol

We have concerned here only the alcohol molecules because acetone is known to thermally decompose^{S2} and its further interaction with OH-groups on the MXenes surface results in the formation of two methanol molecules^{S3}:

$$CH_3COCH_3 = CO + 2CH_3$$

 $2CH_3 + OH^- = 2CH_3OH$

DFT calculations were performed with Vienna Ab-Initio Simulation Package $(VASP)^{S3,S4}$ using the projector augmented-wave method^{S5}. For the exchange and correlation functional we used the Perdew–Burke–Ernzerhof (PBE) version of the generalized gradient approximation^{S6}. The van der Waals interactions were calculated using the Grimme DFT-D3 approach^{S7}. The plane-wave basis energy cutoff was equal to 600 eV. The $4\times4\times1$ Γ -centered k-point mesh and a denser $8\times8\times1$ k-mesh were employed for the geometry optimization and calculation of electronic structure, respectively. A geometry relaxation was performed using the conjugated gradient method. The effective atomic charges are calculated using the Bader (topological) analysis^{S8,S9}.

Supporting Table

Table S1. XPS peak fitting results for as-prepared and oxidized MXenes. The numbers in roundbrackets in column 2 are Ti $2p_{1/2}$ peak energies

Region	Binding energy, eV	Assigned to	Fraction, %
	As-prepa	ared MXene	
Ti 2p _{3/2} (2p _{1/2})	455.1 (461.3)	Ti-C	26.0
	455.8 (461.6)	Ti(II)	22.3
	457.1 (462.9)	Ti(III)	33.7
	458.9 (464.2)	TiO ₂	18.0
O 1s	530.0	TiO ₂	28.9
	531.9	C-Ti-(OH) _x	40.2
	533.5	H ₂ O _{ads}	21.2
	535.4	Al(OF) _x	9.7
C 1s	282.0	Ti-C	25.6
	285.0	C-C/CH _x	61.3
	286.3	C-0	9.1
	289.1	COO	4.0
	Oxidiz	ed MXene	
Ti 2p _{3/2} (2p _{1/2})	455.0 (461.2)	Ti-C	8.7
	457.2 (462.9)	Ti(III)	5.4
	458.9 (464.5)	TiO ₂	85.9
O 1s	530.2	TiO ₂	79.3
	531.9	C-Ti-(OH)x	20.7
C 1s	282.0	Ti-C	6.6
	285.0	C-C/CH _x	84.8
	289.1	COO	8.6

References

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